

SN75LP1185 LOW-POWER MULTIPLE RS-232 DRIVERS AND RECEIVERS

SLLS335A – JANUARY 1999 – REVISED JANUARY 2001

AVAILABLE OPTIONS

T _A	PACKAGED DEVICES		
	PLASTIC SHRINK SMALL-OUTLINE (DB)	PLASTIC SMALL OUTLINE (DW)	PLASTIC DIP (N)
0°C to 70°C	SN75LP1185DBR	SN75LP1185DW	SN75LP1185N

The DB package is only available taped and reeled. The DW package also is available taped and reeled. Add the suffix R to device type (e.g., SN75LP1185DWR).

Function Tables

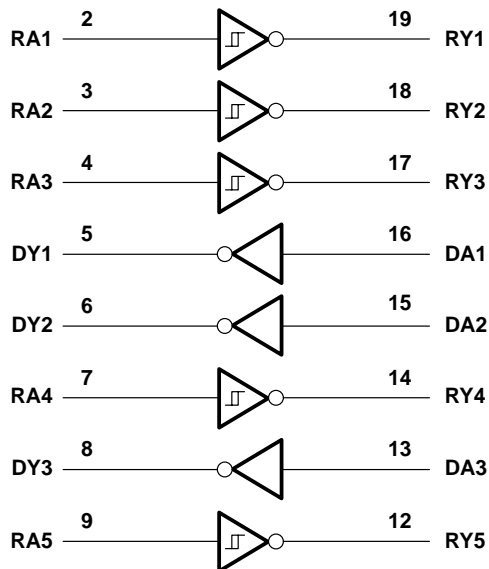
DRIVER

INPUT DA	OUTPUT DY
H	L
L	H
Open	L

RECEIVER

INPUT RA	OUTPUT RY
H	L
L	H
Open	H

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Positive supply-voltage range (see Note 1): V_{CC}	–0.5 V to 7 V
V_{DD}	–0.5 V to 15 V
Negative supply-voltage range, V_{SS} (see Note 1)	0.5 V to –15 V
Input-voltage range, V_I : Receiver (RA)	–30 V to 30 V
Driver (DA)	–0.5 V to $V_{CC} + 0.4$ V
Output-voltage range, V_O : Receiver (RY)	–0.5 V to 6 V
Driver (DY)	–15 V to 15 V
Electrostatic discharge: Bus pins (human-body model) (see Note 2)	Class 3: 15 kV
Bus pins (machine model)	500 V
All pins (human-body model) (see Note 2)	Class 3: 5 kV
All pins (machine model)	400 V
Package thermal impedance, θ_{JA} (see Note 3): DB package	70°C/W
DW package	58°C/W
N package	69°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T_{stg}	65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to network ground terminal, unless otherwise noted.
 2. Per MIL-STD-883, Method 3015.7
 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage (see Note 4)	4.75	5	5.25	V
V_{DD}	Supply voltage (see Note 5)	9	12	15	V
V_{SS}	Supply voltage (see Note 5)	–9	–12	–15	V
V_{IH}	High-level input voltage		2		V
V_{IL}	Low-level input voltage			0.8	V
V_I	Receiver input voltage		–25	25	V
I_{OH}	High-level output current			–1	mA
I_{OL}	Low-level output current			2	mA
T_A	Operating free-air temperature	0		70	°C

- NOTES: 4. V_{CC} cannot be greater than V_{DD} .
 5. The device operates down to $V_{DD} = V_{CC}$ and $|V_{SS}| = V_{CC}$, but supply currents increase and other parameters may vary slightly from the data sheet limits.



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supply currents over the recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply current for V_{CC} , I_{CC}	$V_{DD} = 9\text{ V}$, $V_{SS} = -9\text{ V}$			1000	μA
	$V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$			1000	
Supply current for V_{DD} , I_{DD}	No load, All inputs at minimum V_{OH} or maximum V_{OL}	$V_{DD} = 9\text{ V}$, $V_{SS} = -9\text{ V}$		800	
		$V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$		800	
Supply current for V_{SS} , I_{SS}		$V_{DD} = 9\text{ V}$, $V_{SS} = -9\text{ V}$		-625	
		$V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$		-625	

driver electrical characteristics over the recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V_{OH} High-level output voltage	$V_{IL} = 0.8\text{ V}$, $R_L = 3\text{ k}\Omega$, See Figure 1	$V_{DD} = 9\text{ V}$, $V_{SS} = -9\text{ V}$	5	5.8	6.6	V
		$V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$, See Note 6	5	5.8	6.6	
V_{OL} Low-level output voltage	$V_{IH} = 2\text{ V}$, $R_L = 3\text{ k}\Omega$, See Figure 1	$V_{DD} = 9\text{ V}$, $V_{SS} = -9\text{ V}$	-5	-5.8	-6.9	V
		$V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$, See Note 6	-5	-5.9	-6.9	
I_{IH} High-level input current	V_I at V_{CC}			1	μA	
I_{IL} Low-level input current	V_I at GND			-1	μA	
$I_{OS(H)}$ Short-circuit high-level output current	$V_O = \text{GND}$ or V_{SS} . See Figure 2 and Note 7		-30	-55	mA	
$I_{OS(L)}$ Short-circuit low-level output current	$V_O = \text{GND}$ or V_{DD} . See Figure 2 and Note 7		30	55	mA	
r_o Output resistance	$V_{DD} = V_{SS} = V_{CC} = 0$, $V_O = 2\text{ V}$	300			Ω	

NOTES: 6. Maximum output swing is clamped nominally at $\pm 6\text{ V}$ to enable the higher data rates associated with this device and to reduce EMI emissions. The driver outputs may slightly exceed the maximum output voltage over the full V_{CC} and temperature ranges.
7. Not more than one output should be shorted at one time.



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driver switching characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT		
t_{PHL}	Propagation delay time, high- to low-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, $C_L = 15\text{ pF}$, See Figure 1	300	800	1600	ns		
t_{PLH}	Propagation delay time, low- to high-level output	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, $C_L = 15\text{ pF}$, See Figure 1	300	800	1600	ns		
t_{TLH}	Transition time, low- to high-level output	$V_{CC} = 5\text{ V}$, $V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$, $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, See Figure 1 and Note 9	Using $V_{TR} = 10\%$ -to-90% transition region, Driver speed = 250 kbit/s, $C_L = 15\text{ pF}$, See Note 8		375	2240	ns	
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = 250 kbit/s, $C_L = 15\text{ pF}$		200	1500		
			Using $V_{TR} = \pm 2\text{ V}$ transition region, Driver speed = 250 kbit/s, $C_L = 15\text{ pF}$		133	1000		
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = 125 kbit/s, $C_L = 2500\text{ pF}$			2750		
t_{THL}	Transition time, high- to low-level output	$V_{CC} = 5\text{ V}$, $V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$, $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, See Figure 1 and Note 9	Using $V_{TR} = 10\%$ -to-90% transition region, Driver speed = 250 kbit/s, $C_L = 15\text{ pF}$, See Note 8		375	2240	ns	
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = 250 kbit/s, $C_L = 15\text{ pF}$		200	1500		
			Using $V_{TR} = \pm 2\text{ V}$ transition region, Driver speed = 250 kbit/s, $C_L = 15\text{ pF}$		133	1000		
			Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = 125 kbit/s, $C_L = 2500\text{ pF}$			2750		
SR	Output slew rate	$V_{CC} = 5\text{ V}$, $V_{DD} = 12\text{ V}$, $V_{SS} = -12\text{ V}$	Using $V_{TR} = \pm 3\text{ V}$ transition region, Driver speed = 0 to 250 kbit/s, $C_L = 15\text{ pF}$		4	20	30	V/ μ s

NOTES: 8. Equivalent to the SN75C185. The SN75LP1185 output-voltage swing is clamped to about 70% of the typical SN75C185 output-voltage swing, and the specified limits reflect the reduced output swing.

9. Maximum output swing is limited to $\pm 6\text{ V}$ to enable the higher data rates associated with this device and to reduce EMI emissions.

receiver electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage	See Figure 3	1.6	2	2.55	V
V_{IT-}	Negative-going input threshold voltage	See Figure 3	0.6	1	1.45	V
V_{HYS}	Input hysteresis, $V_{IT+} - V_{IT-}$	See Figure 3	600	1000		mV
V_{OH}	High-level output voltage	$I_{OH} = -1\text{ mA}$	2.5	3.9		V
V_{OL}	Low-level output voltage	$I_{OL} = 2\text{ mA}$		0.33	0.5	V
I_{IH}	High-level input current	$V_I = 3\text{ V}$	0.43	0.6	1	mA
		$V_I = 25\text{ V}$	3.6	5.1	8.3	
I_{IL}	Low-level input current	$V_I = -3\text{ V}$	-0.43	-0.6	-1	mA
		$V_I = -25\text{ V}$	-3.6	-5.1	-8.3	
$I_{OS(H)}$	Short-circuit high-level output current	$V_O = 0$, See Figure 5 and Note 7			-20	mA
$I_{OS(L)}$	Short-circuit low-level output current	$V_O = V_{CC}$, See Figure 5 and Note 7			20	mA
R_{IN}	Input resistance	$V_I = \pm 3\text{ V}$ to $\pm 25\text{ V}$	3	5	7	k Ω

NOTE 7: Not more than one output should be shorted at one time.



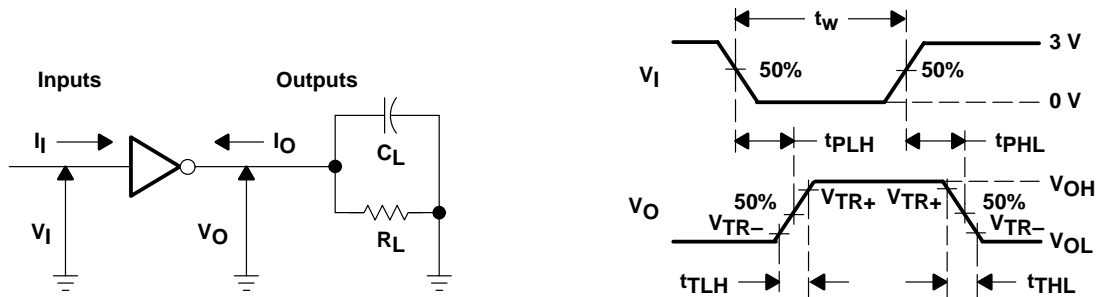
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receiver switching characteristics over recommended operating free-air temperature range, $C_L = 50$ pF (unless otherwise noted) (see Figure 4)

PARAMETER		MIN	TYP	MAX	UNIT
t_{PHL}	Propagation delay time, high- to low-level output		400	900	ns
t_{PLH}	Propagation delay time, low- to high-level output		400	900	ns
t_{TLH}	Transition time, low- to high-level output		200	500	ns
t_{THL}	Transition time, high- to low-level output		200	400	ns
$t_{SK(p)}$	Pulse skew $ t_{PLH} - t_{PHL} $		200	425	ns

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generator has the following characteristics:
 For $C_L < 1000$ pF: $t_w = 4 \mu s$, PRR = 250 kbit/s, $Z_O = 50 \Omega$, t_r and $t_f < 50$ ns.
 For $C_L = 2500$ pF: $t_w = 8 \mu s$, PRR = 125 kbit/s, $Z_O = 50 \Omega$, t_r and $t_f < 50$ ns.
 B. C_L includes probe and jig capacitance.

Figure 1. Driver Parameter Test Circuit and Waveform

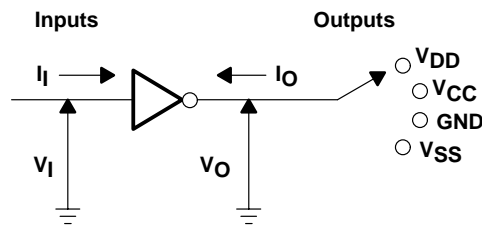


Figure 2. Driver I_{OS} Test

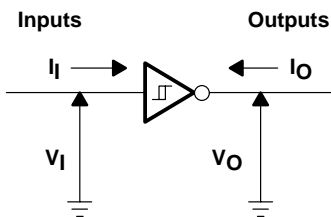
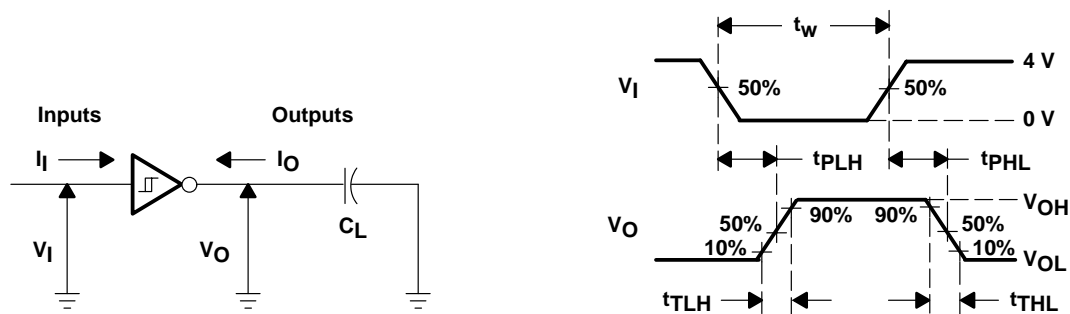


Figure 3. Receiver V_{IT} Test

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The pulse generator has the following characteristics: $t_w = 4 \mu s$, PRR = 250 kbit/s, $Z_O = 50 \Omega$, t_r and $t_f < 50 ns$.
B. C_L includes probe and jig capacitance.

Figure 4. Receiver Parameter Test Circuit and Waveform

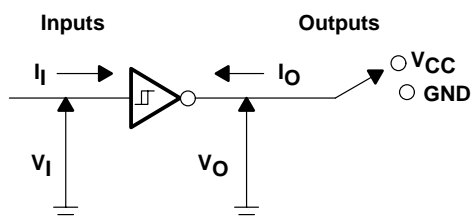


Figure 5. Receiver I_{OS} Test

APPLICATION INFORMATION

Diodes placed in series with the V_{DD} and V_{SS} leads protect the SN75LP1185 in the fault condition when the device outputs are shorted to $\pm 15 V$ and the power supplies are at low voltage and provide low-impedance paths to ground (see Figure 6).

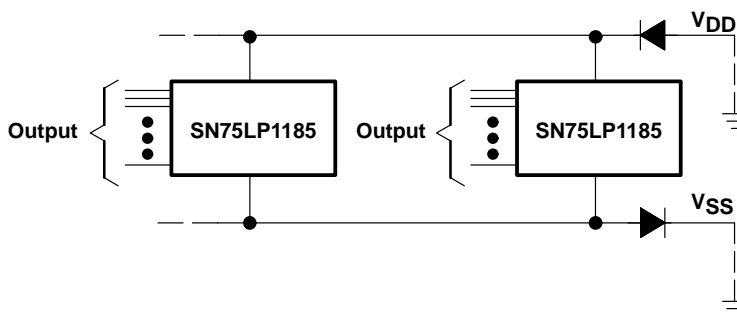


Figure 6. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F

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Mailing Address:

Texas Instruments
Post Office Box 655303
Dallas, Texas 75265